



MARRI LAXMAN REDDY INSTITUTE OF TECHNOLOGY AND MANAGEMENT

(AN AUTONOMOUS INSTITUTION)

(Approved by AICTE, New Delhi & Affiliated to JNTUH, Hyderabad)

Accredited by NBA and NAAC with 'A' Grade & Recognized Under Section 2(f) & 12(B) of the UGC act, 1956

II B.Tech I Sem Regular End Examination, February-2022

Analog Electronics**(EEE)****Max. Marks: 70**

Note: 1. Question paper consists: Part-A and Part-B.

2. In Part – A, answer all questions which carries 20 marks.

3. In Part – B, answer any one question from each unit.

Each question carries 10 marks and may have a, b as sub questions.

PART- A**(10*2 Marks = 20 Marks)**

- | | | | | |
|-------|---|----|-----|-----|
| 1. a) | What are the conditions for the approximate h-parameter model? | 2M | C01 | BL1 |
| b) | Difference between half-wave rectifier and full-wave rectifier | 2M | C01 | BL2 |
| c) | Draw the characteristics of N-channel enhancement MOSFET | 2M | C02 | BL1 |
| d) | Draw the high frequency equivalent circuit of MOSFET | 2M | C02 | BL1 |
| e) | Discuss about Class-A power amplifier | 2M | C03 | BL2 |
| f) | What are the drawbacks of transformer coupled power amplifiers | 2M | C03 | BL1 |
| g) | What is the effect of -ve feedback on the input impedance of an amplifier | 2M | C04 | BL1 |
| h) | State Barkhausen's criteria | 2M | C04 | BL1 |
| i) | What are ideal characteristics of operational amplifier | 2M | C05 | BL1 |
| j) | Define Slew rate. | 2M | C05 | BL1 |

PART- B**(10*5 Marks = 50 Marks)**

- | | | | | |
|------|--|----|-----|-----|
| 2 a) | With circuit and necessary waveforms explain the operation of full-wave rectifier. | 5M | C01 | BL4 |
| b) | Illustrate the working principle of pn junction diode in forward bias. | 5M | C01 | BL3 |

OR

- | | | | | |
|---|--|-----|-----|-----|
| 3 | Draw the circuit of fixed bias CE amplifier. In a silicon transistor with a fixed bias, $V_{CC} = 9\text{ V}$, $R_C = 3\text{ k}\Omega$, $R_B = 8\text{ k}\Omega$, $\beta = 50$, $V_{BE} = 0.7\text{ V}$. Find the operating point. | 10M | C01 | BL3 |
|---|--|-----|-----|-----|

- | | | | | |
|------|---|----|-----|-----|
| 4 a) | Explain the construction and working of n-type Enhancement MOSFET | 5M | C02 | BL4 |
| b) | Distinguish between common-source, common-gate and common-drain amplifiers of MOSFET. | 5M | C02 | BL2 |

OR

- | | | | | |
|---|--|-----|-----|-----|
| 5 | Explain how MOSFET acts as a switch. Compare n-type and p-type MOSFET. | 10M | C02 | BL4 |
|---|--|-----|-----|-----|

6	a)	Classify power amplifiers based on operating point selection with neat diagram.	5M	C03	BL2
	b)	Draw the circuit diagram of complementary symmetry class-B push pull amplifier and explain its operation.	5M	C03	BL4
OR					
7		Draw the circuit diagram of a cascade amplifier and derive its overall voltage gain and impedance from its equivalent circuit	10M	C03	BL6
8	a)	Calculate the voltage gain, input impedance and output impedance of a voltage series feedback amplifier having an open loop gain $A=300$, $R_i=1.5K\Omega$, $R_0=50K\Omega$ and $\beta=1/20$.	5M	C04	BL3
	b)	Discuss the effect of negative feedback with respect to closed loop gain, bandwidth.	5M	C04	BL2
OR					
9		Perform the generalized analysis of LC oscillators with suitable block diagram and obtain the condition for Hartley and colpitt's oscillators	10M	C04	BL4
10	a)	Explain how an op-amp can be used as integrator? Also derive expression for the output.	5M	C05	BL4
	b)	Calculate output voltage of a non-inverting amplifier for values of $V_1=2V$, $R_f=500K\Omega$ and $R_1=100K\Omega$.	5M	C05	BL3
OR					
11		Draw the block schematic of an op-amp and explain the functions of each block	10M	C05	BL4

---oo0oo---